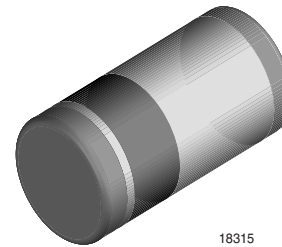


Zener Diodes

Features

- Silicon Planar Power Zener Diodes
- For use in stabilizing and clipping circuits with high power rating
- The Zener voltages are graded according to the international E 12 standard
Smaller voltage tolerances are available upon request
- These diodes are also available in the DO-41 case with the type designation ZPU100 ... ZPU180.
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



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Mechanical Data

Case: MELF Glass case

Weight: approx. 135 mg

Packaging Codes/Options:

GS18/ 5 k per 13" reel (12 mm tape), 10 k/box

GS08/ 1.5 k per 7" reel (12 mm tape), 12 k/box

Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Zener current (see table "Characteristics")				
Power dissipation	$T_{amb} = 25\text{ }^{\circ}\text{C}$	P_{tot}	1.0 ¹⁾	W

¹⁾ Valid provided that electrodes are kept at ambient temperature.

Thermal Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air		R_{thJA}	170 ¹⁾	K/W
Junction temperature		T_j	175	$^{\circ}\text{C}$
Storage temperature range		T_{stg}	- 55 to + 175	$^{\circ}\text{C}$

¹⁾ Valid provided that electrodes are kept at ambient temperature.

Electrical Characteristics

Partnumber	Zener Voltage ¹⁾		Dynamic Resistance		Test Current	Temperature Coefficient of Zener Voltage		Reverse Voltage	Admissible Zener Current ²⁾
	V_Z at I_{ZT}		r_{zj} at I_{ZT} , $f = 1$ kHz			I_{ZT}	a_{VZ} at I_{ZT}		
	V	V	Ω	Ω	mA	$10^{-4}/^{\circ}\text{C}$		V	mA
ZMU100	88	110	140	< 300	5	+ 9	+ 13	> 75	7
ZMU120	107	134	170	< 330	5	+ 9	+ 13	> 90	6
ZMU150	130	165	200	< 360	5	+ 9	+ 13	> 112	5
ZMU180	160	200	220	< 380	5	+ 9	+ 13	> 134	4

¹⁾ Tested with pulses $t_p = 5$ ms

²⁾ Valid provided that electrodes are kept at ambient temperature

Typical Characteristics ($T_{amb} = 25^{\circ}\text{C}$ unless otherwise specified)

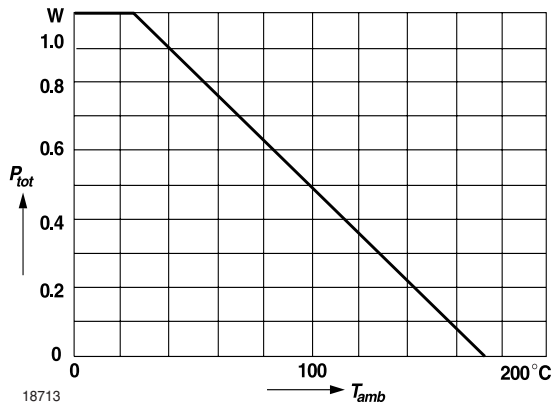


Figure 1. Admissible Power Dissipation vs. Ambient Temperature

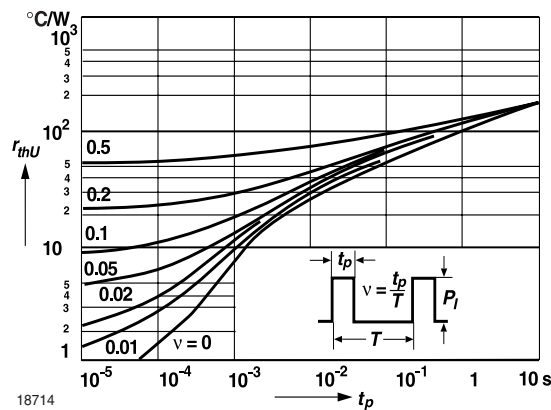
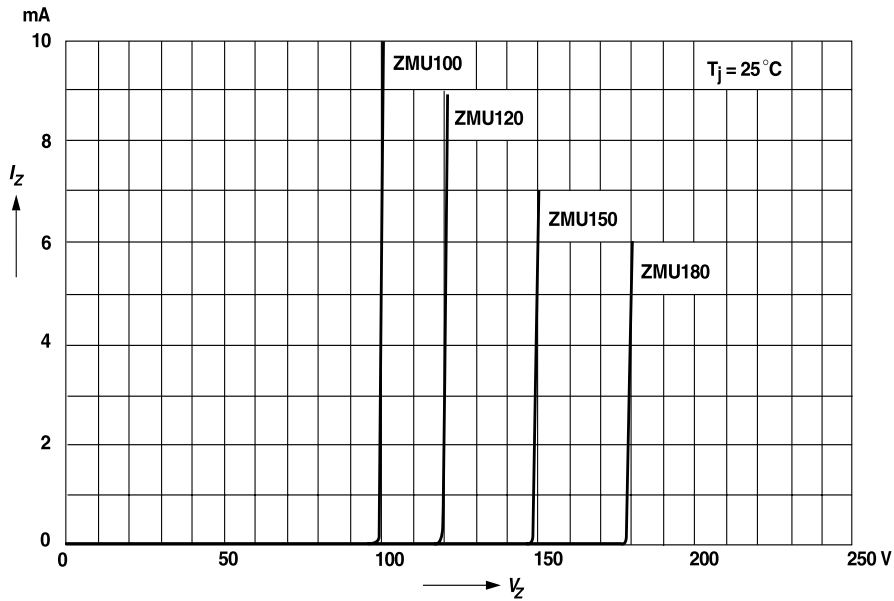


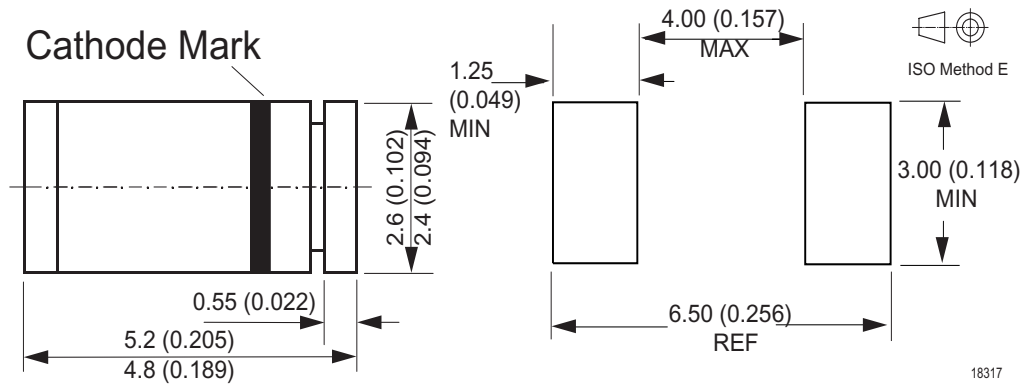
Figure 2. Pulse Thermal Resistance vs. Pulse Duration



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Figure 3. Breakdown Characteristics

Package Dimensions in mm (Inches)



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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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